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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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2SK1374

Silicon N-channel MOSFET

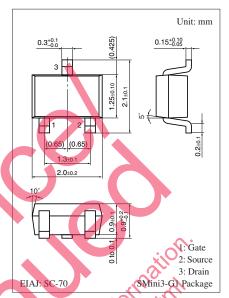
For switching circuits

■ Features

- High-speed switching
- Wide frequency band
- Incorporating a built-in gate protection-diode
- Allowing 2.5 V drive

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Drain-source voltage	V_{DS}	50	V	
Gate-source voltage (Drain open)	V_{GSO}	10	V	
Drain current	I_D	50	mA	
Peak drain current	I_{DP}	100	mA	
Power dissipation	P_{D}	150	mW	
Channel temperature	T _{ch}	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	



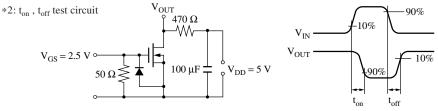
Marking Symbol: 4V

■ Electrical Characteristics T_a = 25°C

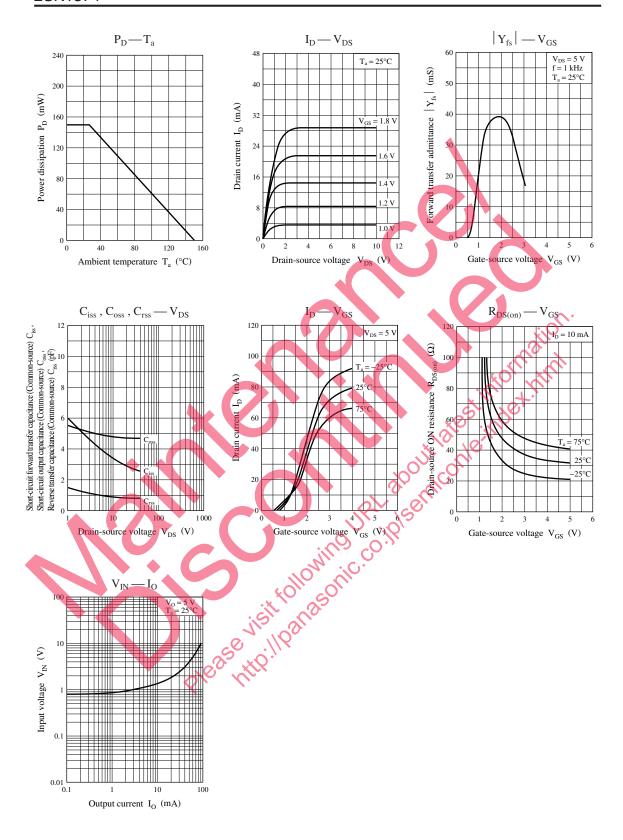
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source surrender voltage	V_{DSS}	$I_D = 10 \mu\text{A}, V_{GS} = 0$	50	100		V
Drain-source cutoff current	I_{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0$			1.0	μΑ
Gate-source cutoff current	I _{GSS}	$V_{GS} = 10 \text{ V}, V_{DS} = 0$			1.0	μΑ
Gate threshold voltage	V_{th}	$I_D = 100 \mu\text{A}, V_{DS} = 5 \text{V}$	0.5	0.8	1.1	V
Forward transfer admittance	Y _{fs}	$I_D = 10 \text{ mA}, V_{DS} = 5 \text{ V}, f = 1 \text{ kHz}$	20	39		mS
Drain-source ON resistance	R _{DS(on)}	$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$		27	50	Ω
Short-circuit forward transfer capacitance (Common source)	C _{iss}	$V_{DS} = 5 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$		4.5		pF
Short-circuit output capacitance (Common source)	Coss	11/2 and		4.1		pF
Reverse transfer capacitance (Common source)	$\mathcal{C}_{\mathrm{rss}}$	<i>S</i>		1.2		pF
Turn-on time *1, 2	t _{on}	$V_{DD} = 5 \text{ V}, R_L = 470 \Omega, V_{GS} = 0 \text{ V to } 2.5 \text{ V}$		0.2		μs
Turn-off time *1, 2	t _{off}	$V_{DD} = 5 \text{ V}, R_L = 470 \Omega, V_{GS} = 2.5 \text{ V to } 0 \text{ V}$		0.2		μs

 $Note) \ 1. \ Measuring \ methods \ are \ based \ on \ JAPANESE \ INDUSTRIAL \ STANDARD \ JIS \ C \ 7030 \ measuring \ methods \ for \ transistors.$

2. *1: Pulse measurement



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